



PBSS5130PAP,115 Information



For Reference Only

Part Number PBSS5130PAP,115 **Manufacturer** Nexperia USA Inc.

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Arrays

Description TRANS 2PNP 30V 1A 6HUSON

Package 6-UDFN Exposed Pad

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









PBSS5130PAP,115 Specifications

Manufacturer Part Number	PBSS5130PAP,115
Manufacturer	Nexperia USA Inc.
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Arrays
Package	6-UDFN Exposed Pad
Series	-
Transistor Type	2 PNP (Dual)
Current - Collector (Ic) (Max)	1A
Voltage - Collector Emitter Breakdown (Max)	30V
Vce Saturation (Max) @ Ib, Ic	280mV @ 50mA, 1A
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	170 @ 500mA, 2V
Power - Max	510mW
Frequency - Transition	125MHz
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	6-UDFN Exposed Pad
Supplier Device Package	DFN2020-6
	Report errors?

PBSS5130PAP,115 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

PBSS5130PAP,115 Payment Methods





















PBSS5130PAP,115 Shipping Methods













If you have any question about PBSS5130PAP,115, please do not hesitate to contact us!

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